NSN 5961-01-106-0802

Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-106-0802 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches Overall Diameter: Between 0.465 inches and 0.485 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 6.50 amperes source cutoff current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No